



PRELIMINARY

**SOLID STATE DEVICES, INC.**  
 14005 Stage Road \* Santa Fe Springs, Ca 90670  
 Phone: (562) 404-4474 \* Fax: (562) 404-1773

**SDR656CTM & Z**

**40AMPS  
 600 VOLTS  
 30 nsec  
 HYPER FAST  
 CENTERTAP RECTIFIER**

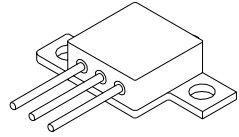
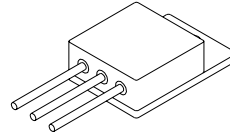
**Designer's Data Sheet**

**FEATURES:**

- Hyper Fast Recovery: 30nsec Maximum
- High Surge Rating
- Low Reverse Leakage Current
- Low Junction Capacitance
- Hermetically Sealed Package
- Gold Eutectic Die Attach Available
- Ultrasonic Aluminum Wire Bonds
- Common Anode and Doubler Versions Available
- TX, TXV and Space Level Screening Available

TO-254

TO-254Z



Maximum Ratings	SYMBOL	VALUE	UNITS
Peak Repetitive Reverse and DC Blocking Voltage SDR656CTM & Z	$V_{RRM}$ $V_{RWM}$ $V_R$	600	Volts
Average Rectified Forward Current. (Resistive load, 60Hz, Sine Wave, $T_A = 25^\circ\text{C}$ ) <u>1/</u>	$I_o$	40	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, $T_A = 25^\circ\text{C}$ ) <u>2/</u>	$I_{FSM}$	200	Amps
Operating and Storage Temperature	$T_{OP}$ & $T_{STG}$	-65 TO +175	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case, each individual diode Junction to Case, <u>1/</u>	$R_{\theta JC}$	2.0 1.0	$^\circ\text{C/W}$

1/ Both legs tied together

2/ Per leg

**NOTE:** All specifications are subject to change without notification.  
 SCD's for these devices should be reviewed by SSDI prior to release.

**DATA SHEET #: RC0028A**

# SDR656CTM & Z

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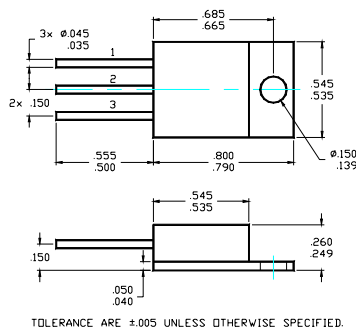
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Electrical Characteristics (per leg)	SYMBOL	VALUE	UNITS
<b>Instantaneous Forward Voltage Drop</b> ( $I_F = 10A$ $T_A = 25^\circ C$ , 300 $\mu$ sec pulse ) ( $I_F = 20A$ $T_A = 25^\circ C$ , 300 $\mu$ sec pulse )	$V_F$	<b>1.35</b>	$V_{DC}$
		<b>1.55</b>	$V_{DC}$
<b>Instantaneous Forward Voltage Drop</b> ( $I_F = 10A$ $T_A = 100^\circ C$ , 300 $\mu$ sec pulse ) ( $I_F = 10A$ $T_A = -55^\circ C$ , 300 $\mu$ sec pulse )	$V_F$	<b>1.25</b>	$V_{DC}$
		<b>1.45</b>	$V_{DC}$
<b>Reverse Leakage Current</b> (Rated $V_R$ , $T_A = 25^\circ C$ , 300 $\mu$ s pulse minimum )	$I_R$	<b>50</b>	$\mu A$
<b>Reverse Leakage Current</b> (Rated $V_R$ , $T_A = 100^\circ C$ , 300 $\mu$ s pulse minimum )	$I_R$	<b>5</b>	mA
<b>Junction Capacitance</b> ( $V_R = 10V_{DC}$ , $T_A = 25^\circ C$ , $f = 1MHz$ )	$C_J$	<b>50</b>	pf
<b>Reverse Recovery Time</b> ( $T_A = 25^\circ C$ , $I_F = 0.5A$ , $I_R = 1.0A$ , $I_{RR} = 0.25A$ )	$T_{RR}$	<b>30</b>	nsec

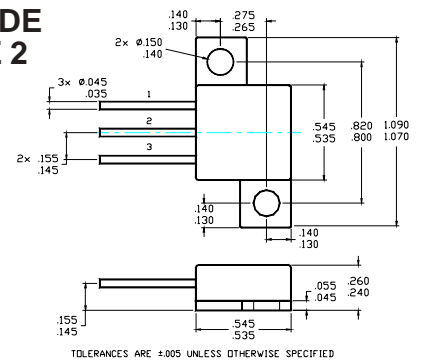
## CASE OUTLINE: TO-254

- PIN 1: ANODE 1
- PIN 2: CATHODE
- PIN 3: ANODE 2



## CASE OUTLINE: TO-254Z

- PIN 1: ANODE 1
- PIN 2: CATHODE
- PIN 3: ANODE 2



## TYPICAL OPERATING CURVES

$T_A = 25^\circ C$  Unless otherwise specified

